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Team Nexperia

PEMH14; PUMH14

NPN/NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = open Rev. 03 — 15 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN/NPN Resistor-Equipped Transistors (RET).

Table 1. Product overview

Type number	Package		NPN/PNP	PNP/PNP
	NXP	JEITA	complement	complement
PEMH14	SOT666	-	PEMD14	PEMB14
PUMH14	SOT363	SC-88	PUMD14	PUMB14

1.2 Features

- Built-in bias resistor
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current (DC)		-	-	100	mA
R1	bias resistor 1 (input)		33	47	61	kΩ



NPN/NPN resistor-equipped transistors; R1 = 47 kΩ, R2 = open

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Symbol
1	GND (emitter) TR1		
2	input (base) TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	
			1 2 3

3. Ordering information

Table 4. Ordering information				
Type number Packag				
	Name	Description	Version	
PEMH14	-	plastic surface mounted package; 6 leads	SOT666	
PUMH14	SC-88	plastic surface mounted package; 6 leads	SOT363	

4. Marking

Table 5.Marking codes	
Type number	Marking code ^[1]
PEMH14	5C
PUMH14	H1*

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

sym090

NPN/NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = open

5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
lo	output current (DC)		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363		[1] -	200	mW
	SOT666		<u>[1][2]</u> _	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363		[1] -	300	mW
	SOT666		[1][2] _	300	mW

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

6. Thermal characteristics

Table 7.	Thermal characteristics	6				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT363		<u>[1]</u> -	-	625	K/W
	SOT666		<u>[1][2]</u> _	-	625	K/W
Per devic	ce					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT363		<u>[1]</u> -	-	416	K/W
	SOT666		<u>[1][2]</u> _	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

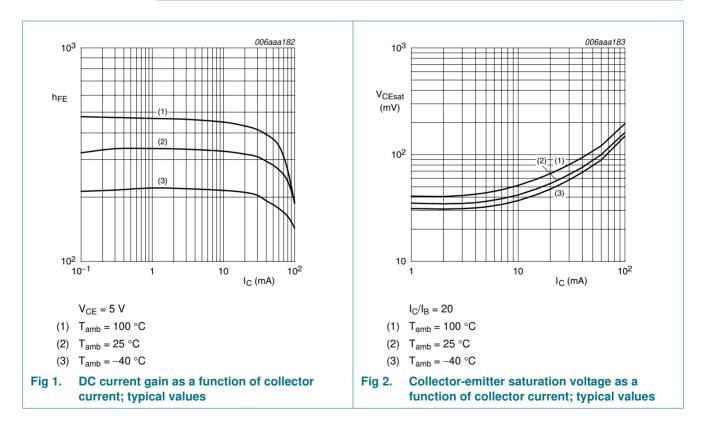
NPN/NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = open

Characteristics 7.

Table 8. **Characteristics** Τ

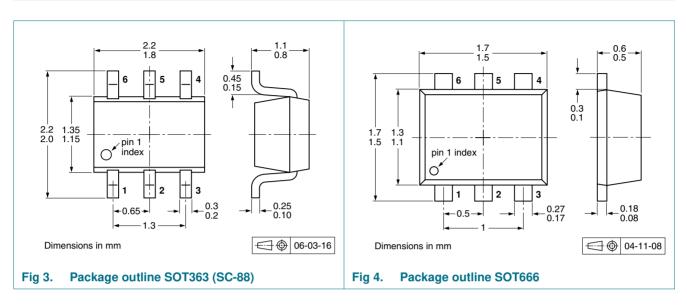
「 _{amb} = 25 ℃ unless	otherwise	specified.
--------------------------------	-----------	------------

4						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	CEO collector-emitter	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	-	-	1	μA
cut-off current	$\label{eq:Vce} \begin{array}{l} V_{CE} = 30 \ V; \ I_{B} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$	-	-	50	μA	
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C}$ = 10 mA; $I_{\rm B}$ = 0.5 mA	-	-	150	mV
R1	bias resistor 1 (input)		33	47	61	kΩ
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	-	-	2.5	pF



NPN/NPN resistor-equipped transistors; R1 = 47 kΩ, R2 = open

8. Package outline



9. Packing information

Table 9.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packi	ng qua	ntity	
			:	3000	4000	8000	10000
PEMH14	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-
		4 mm pitch, 8 mm tape and reel		-	-115	-	-
PUMH14	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-	-165

[1] For further information and the availability of packing methods, see <u>Section 12</u>.

[2] T1: normal taping

[3] T2: reverse taping

NPN/NPN resistor-equipped transistors; R1 = 47 kΩ, R2 = open

10. Revision history

Table 10. Revision his	tory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PEMH14_PUMH14_3	20091115	Product data sheet	-	PEMH14_PUMH14_2
 Modifications: This data sheet was changed to reflect the new company name NXP Sincluding new legal definitions and disclaimers. No changes were made content. 				
	 Figure 3 "Pace 	kage outline SOT363 (SC	- <u>88)"</u> : updated	
PEMH14_PUMH14_2	20050429	Product data sheet	-	PUMH14_1
PUMH14_1	20031016	Product specification	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PEMH14; PUMH14

NPN/NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = open

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